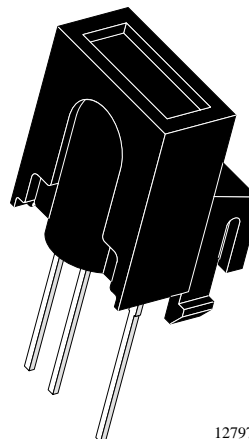


Photo Modules for PCM Remote Control Systems

Available types for different carrier frequencies

Type	f ₀	Type	f ₀
TSOP1130KS1	30 kHz	TSOP1133KS1	33 kHz
TSOP1136KS1	36 kHz	TSOP1137KS1	36.7 kHz
TSOP1138KS1	38 kHz	TSOP1140KS1	40 kHz
TSOP1156KS1	56 kHz		



12797

Description

The TSOP11..KS1 – series are miniaturized receivers for infrared remote control systems. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter. The demodulated output signal can directly be decoded by a microprocessor.

The main benefit is the operation with short burst transmission codes (e.g. RECS 80) and high data rates.

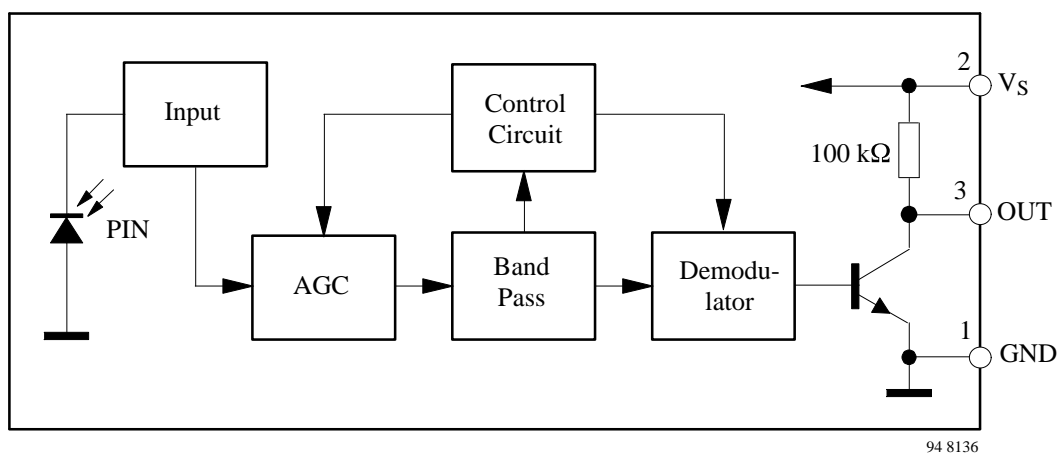
Features

- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against electrical field disturbance
- TTL and CMOS compatibility
- Output active low
- Low power consumption
- High immunity against ambient light

Special Features

- Enhanced data rate of 2400 bit/s
- Operation with short bursts possible (≥ 6 cycles/burst)

Block Diagram



Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$

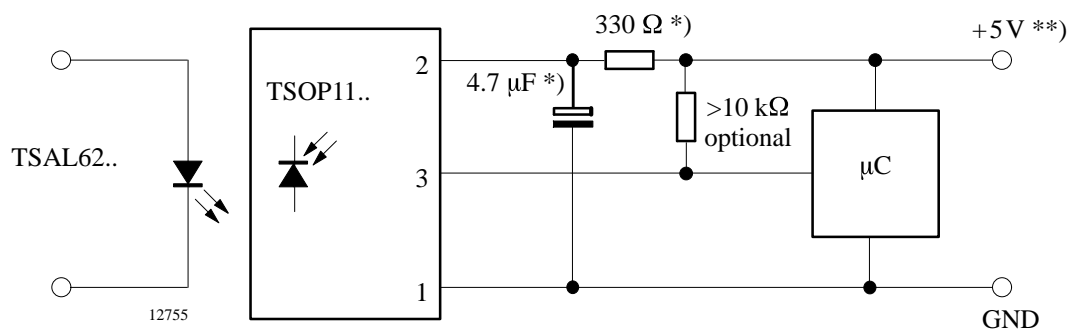
Parameter	Test Conditions	Symbol	Value	Unit
Supply Voltage	(Pin 2)	V_S	-0.3...6.0	V
Supply Current	(Pin 2)	I_S	5	mA
Output Voltage	(Pin 3)	V_O	-0.3...6.0	V
Output Current	(Pin 3)	I_O	5	mA
Junction Temperature		T_j	100	$^{\circ}\text{C}$
Storage Temperature Range		T_{stg}	-25...+85	$^{\circ}\text{C}$
Operating Temperature Range		T_{amb}	-25...+85	$^{\circ}\text{C}$
Power Consumption	($T_{amb} \leq 85^{\circ}\text{C}$)	P_{tot}	50	mW
Soldering Temperature	$t \leq 5\text{ s}$	T_{sd}	260	$^{\circ}\text{C}$

Basic Characteristics

$T_{amb} = 25^{\circ}\text{C}$

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Supply Current (Pin 2)	$V_S = 5\text{ V}, E_v = 0$	I_{SD}	0.4	0.5	0.8	mA
	$V_S = 5\text{ V}, E_v = 40\text{ klx}$, sunlight	I_{SH}		1		mA
Transmission Distance	$E_v = 0$, test signal see fig.8, IR diode TSIP5201, $I_F = 0.4\text{ A}$	d		35		m
Output Voltage Low (Pin 3)	$I_{OSL} = 0.5\text{ mA}, E_e = 0.7\text{ mW/m}^2$, $f = f_o$, test signal see fig.7	V_{OSL}			250	mV
Irradiance (30 – 40 kHz)	Test signal see fig.7	$E_e\text{ min}$		0.4	0.6	mW/m^2
	Test signal see fig.8	$E_e\text{ min}$		0.35	0.5	mW/m^2
Irradiance (56 kHz)	Test signal see fig.7	$E_e\text{ min}$		0.45	0.7	mW/m^2
	Test signal see fig.8	$E_e\text{ min}$		0.40	0.6	mW/m^2
Irradiance	Test signal see fig.7	$E_e\text{ max}$	30			W/m^2
Directivity	Angle of half transmission distance	$\phi_{1/2}$		± 45		deg

Application Circuit



*) only necessary to suppress power supply disturbances

***) tolerated supply voltage range : $4.5\text{ V} < V_S < 5.5\text{ V}$

Typical Characteristics ($T_{amb} = 25^{\circ}C$ unless otherwise specified)

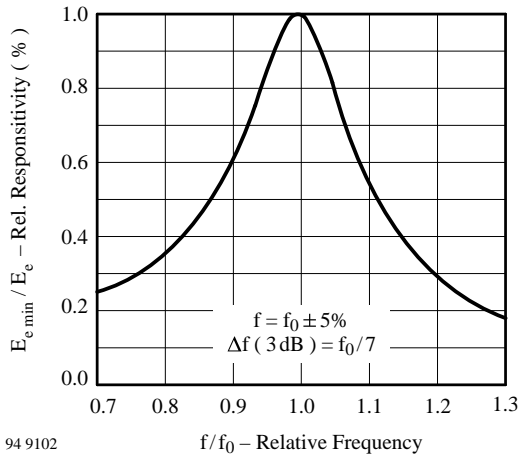


Figure 1. Frequency Dependence of Responsivity

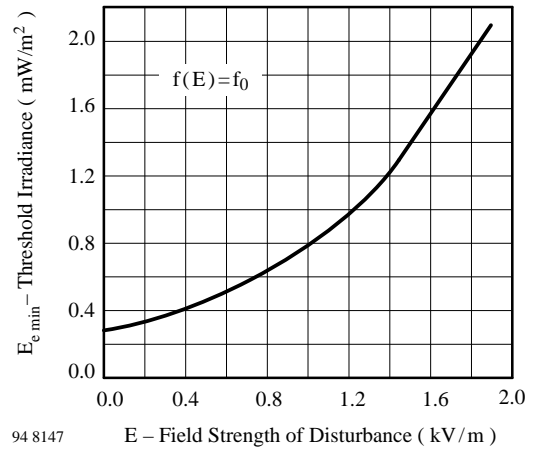


Figure 4. Sensitivity vs. Electric Field Disturbances

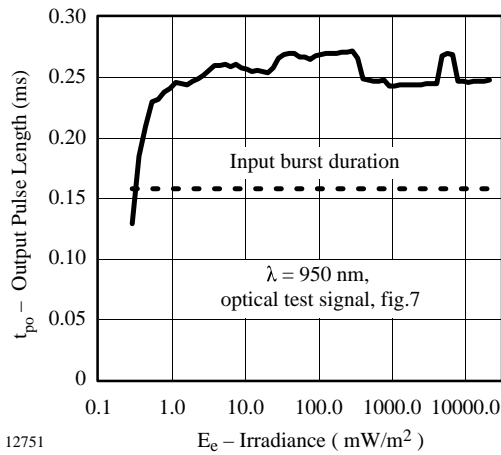


Figure 2. Pulse Length and Sensitivity in Dark Ambient

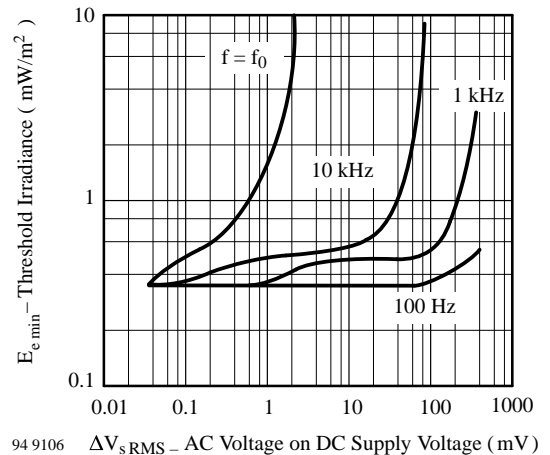


Figure 5. Sensitivity vs. Supply Voltage Disturbances

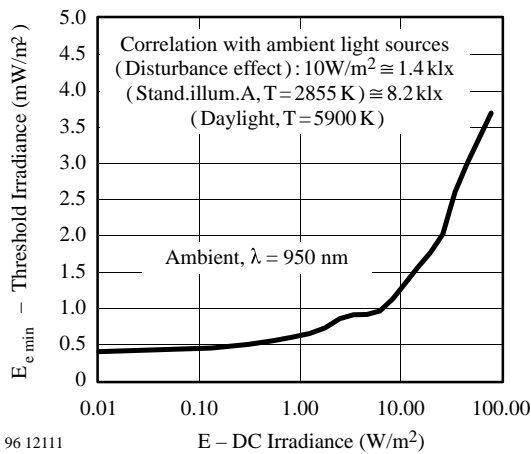


Figure 3. Sensitivity in Bright Ambient

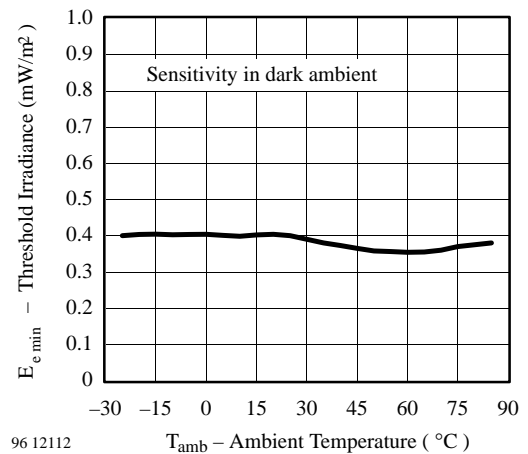


Figure 6. Sensitivity vs. Ambient Temperature

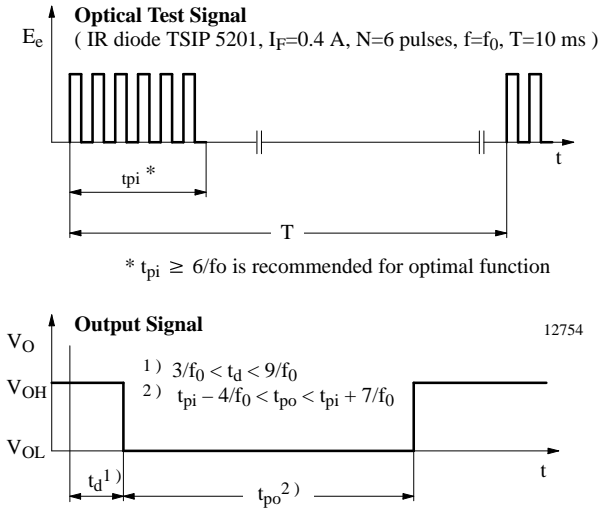


Figure 7. Output Function

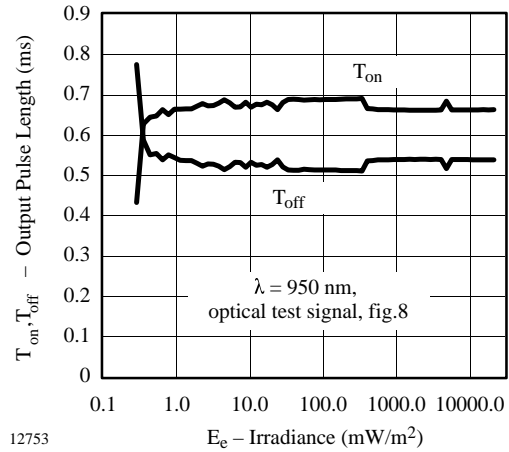


Figure 10. Output Pulse Diagram

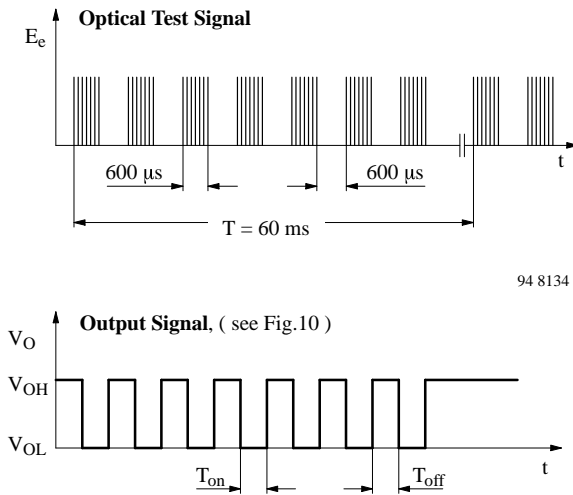


Figure 8. Output Function

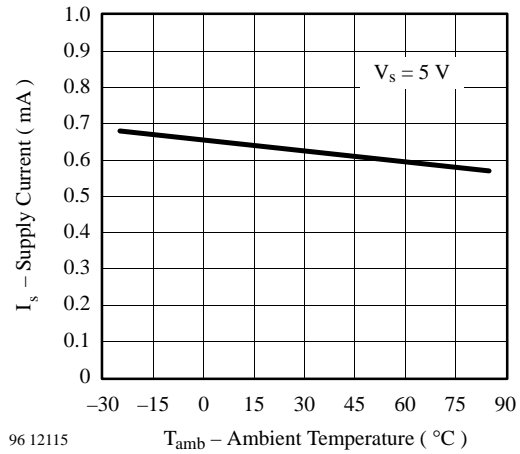


Figure 11. Supply Current vs. Ambient Temperature

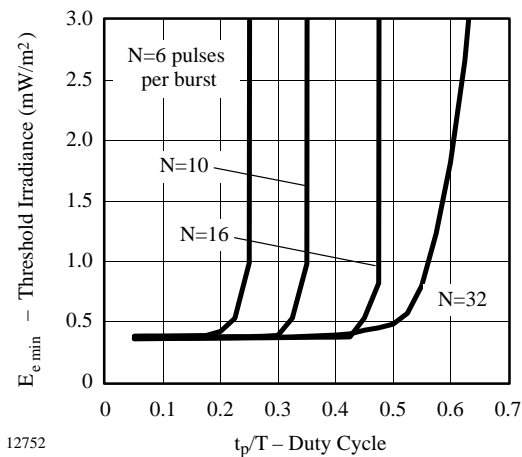


Figure 9. Sensitivity vs. Duty Cycle

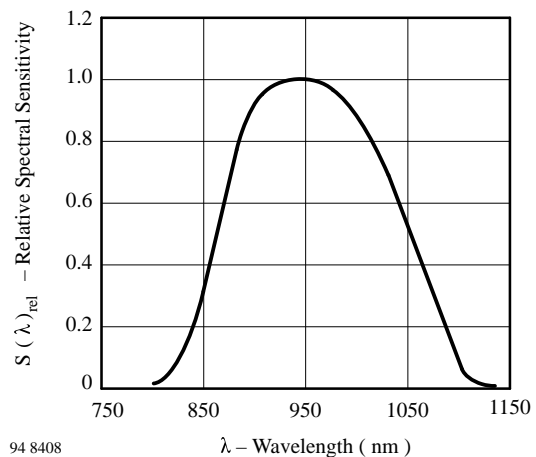


Figure 12. Relative Spectral Sensitivity vs. Wavelength

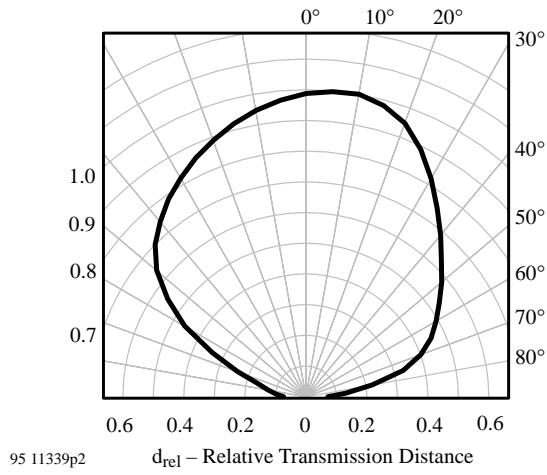


Figure 13. Vertical Directivity ϕ_y

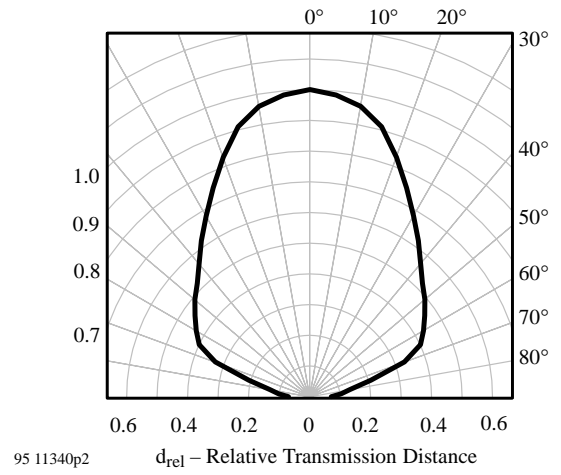
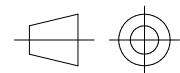
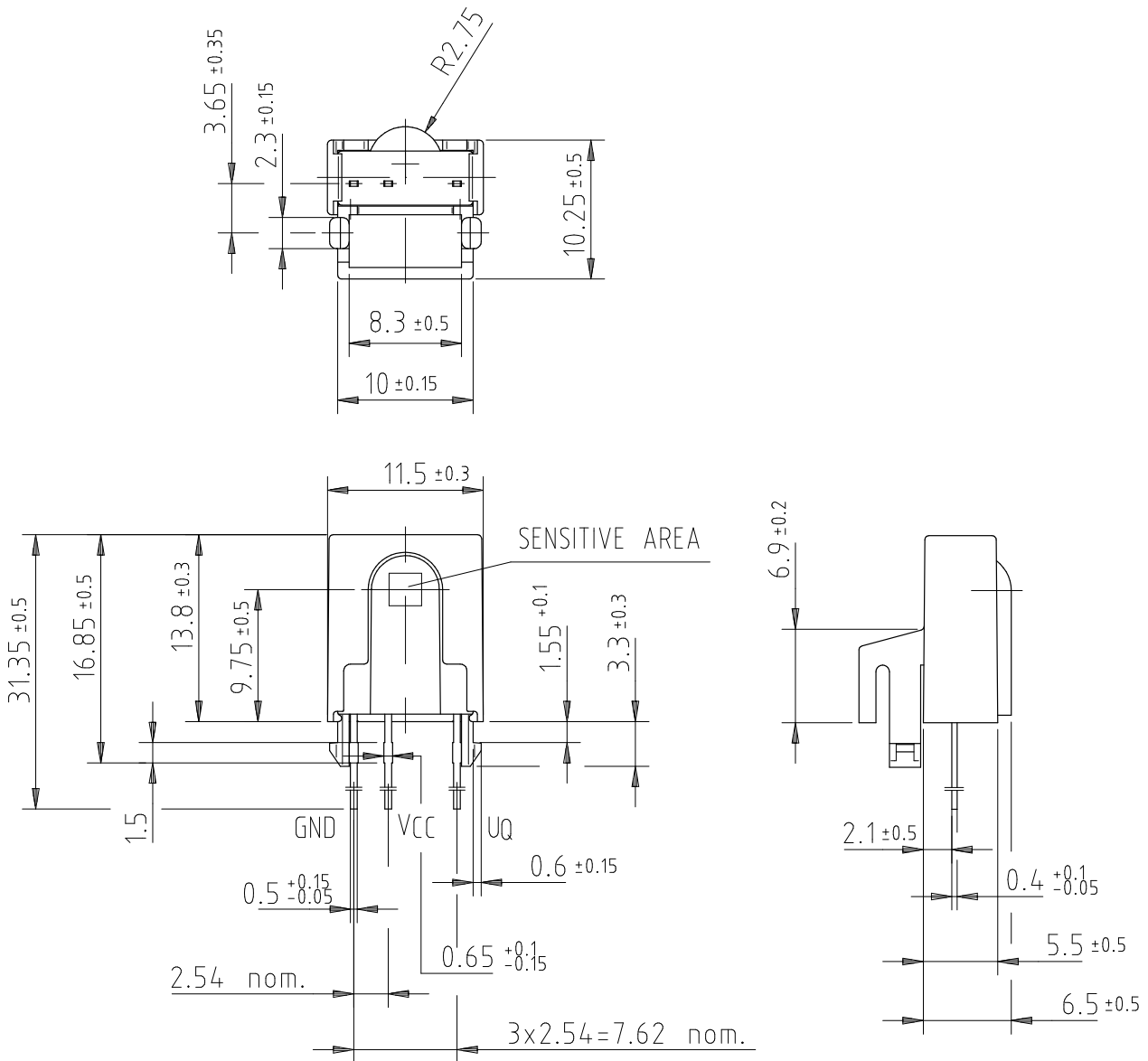


Figure 14. Horizontal Directivity ϕ_x

Dimensions in mm



technical drawings
according to DIN
specifications

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Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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